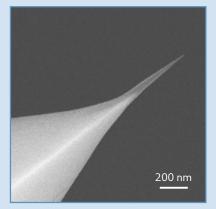
High Aspect Ratio

Provided with

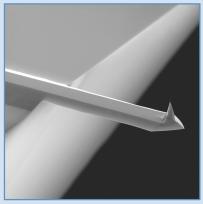
TrueDimensions™

Online access to key probe parameters for every individual tip

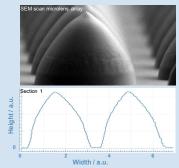




M-CIS SEM scan



SEM scan of an NT-RTESPA AFM probe.



Qualitative representation of a microlens array inspected with M-CIS (disquised customer data).

Type: M-CIS

The industry standard for precise and cost-efficient inspection of contact image sensors (CIS).

M-CIS probe made of high density, diamond-like carbon (HDC/DLC) for reliable and long-lasting high-resolution access to fine structures such as microlens arrays. Extract true depth information and highly precise pattern profiles with considerably reduced tip convolution effects due to the accurately tilt-compensated tip with an aspect ratio better than 1:5.

Features

- Precisely shaped. Conical, rotationally symmetric tip shape fabricated with nanometer precision and an aspect ratio >1:5. Considerable reduction of tip artifacts compared to standard pyramidal Si tips.
- Improved throughput. Diamond-like material properties. Excellent long-term measurement stability for an outstanding cost-performance ratio.
- Quality guaranteed. 100% quality control for every individual tip. Online datasheets including individual dimensional values available 24/7 via QR code.

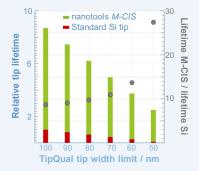
Improved throughput



Tip width versus number of engages of an M-CIS probe (green) compared to a state-of-theart Si probe (red), together with the corresponding linear fits (dashed lines). After 200 engages the tip width of the standard Si tip is considerably increased by $\sim\!32$ %, while the relative tip width increase of the M-CIS probe is $\sim\!7$ %.

Left axis: relative tip lifetime of M-CIS (green bars) and a state-of-the-art Si probes (red bars) depending on the tip qualification tip width limit. With decreasing tip width limit, the enhanced tip lifetime an M-CIS probe becomes more and more pronounced (right axis, grey dots).

At a tip width limit of 50 nm the tip lifetime of the M-CIS probe is more than 25 times larger than that of the standard Si probe.



NT_MCIS_voo20

High Aspect Ratio

Provided with **TrueDimensions™** Online access to key probe parameters for every individual tip

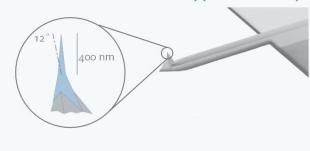


Technical specifications

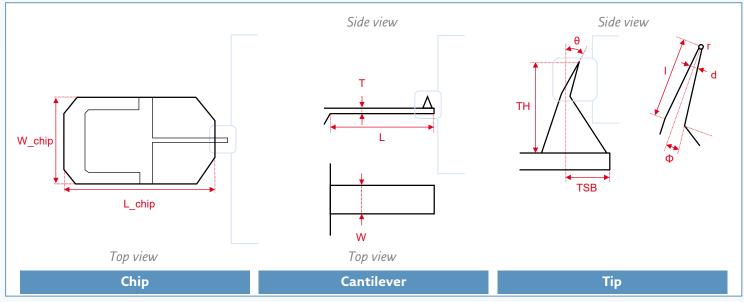
M-CIS

Part number	NT_MCIS_	NT_MCIS_voo20	
Тір			
Material	HDC/DLC		
Shape	conical		
Length / I	400 nm	(±100 nm)	
Width / d	n/a		
Half cone angle / Φ	<4°	(AR > ₅)	
Sharpness (radius) / r	10 nm	(±2 nm)	
Tilt compensation / θ	12°	(±1°)	
Total tip height / TH	15 µm	(10-15 µm)	
Tip set back / TSB	15 µm	(5-25 µm)	
Cantilever			
Material	Si		
Shape	NT-RTESPA		
Length / L	120 µm	$(\pm 5 \mu m)$	
Width / W	30 µm	(±2 µm)	
Thickness / T	4.4 µm	$(\pm 0.5 \mu m)$	
Force constant [1] / k	40 N/m	(±20 N/m)	
Resonance frequency [1] / f	320 kHz	(±50 kHz)	
Tip side coating	none		
Back side coating	reflex		
Chip			
Length / L_chip	3400 µm		
Width / W_chip	1600 µm		
Thickness / T_chip	315 µm		
Alignment grooves	no		

- **Consistent dimensions**
- **Carbon durability**
- Industry proven reliability



[1] Resonance frequency f extracted from LDV measurements; cantilever stiffness k calculated from the (measured) cantilever geometry. Actual values of >90% of all probes are guaranteed to be within the specified range. |n/a|: specification not applicable for this product.



For more information please visit

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ISO 9001 certified quality